

# **isc Silicon PNP Darlington Power Transistor**

BDX54

### **DESCRIPTION**

- · Collector-Emitter Sustaining Voltage-
- :  $V_{CEO(sus)} = -45V(Min)$
- · High DC Current Gain
  - : h<sub>FE</sub>= 750(Min) @I<sub>C</sub>= -3A
- · Low Collector Saturation Voltage
  - :  $V_{CE(sat)} = -2.0 \text{ V(Max)} @ I_C = -3.0 \text{ A}$
- Complement to Type BDX53
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



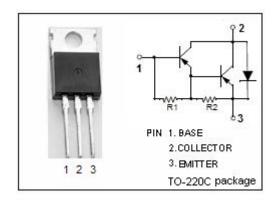
 Designed for general-purpose amplifier and low-speed switching applications.

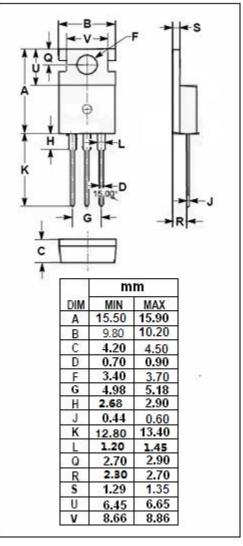
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

7.2552512 110 54.11165(12 25 5)							
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>CBO</sub>	Collector-Base Voltage -45						
V <sub>CEO</sub>	Collector-Emitter Voltage	-45	V				
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V				
Ic	Collector Current-Continuous -8		Α				
ICP	Collector Current-Peak -1		Α				
lв	Base Current-Continuous	-0.2	Α				
Pc	Collector Power Dissipation @ T <sub>C</sub> =25℃	60	W				
TJ	Junction Temperature 150		$^{\circ}$				
T <sub>stg</sub>	Storage Temperature Range	-65~150	$^{\circ}$				

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	1.92	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -50mA; I <sub>B</sub> = 0	-45			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -12mA			-2.0	٧
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -12mA			-2.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -45V; I <sub>E</sub> = 0			-0.2	mA
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = -22V; I <sub>B</sub> = 0			-0.5	mA
І <sub>ЕВО</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-2	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -3A ; V <sub>CE</sub> = -3V	750			

#### **NOTICE:**

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